



**MMDT5401Q** 

#### **150V DUAL PNP SMALL SIGNAL TRANSISTOR IN SOT363**

### Description

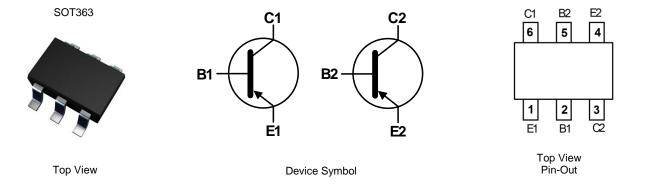
This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

### Features

- **Epitaxial Planar Die Construction**
- Complementary NPN Type Available (MMDT5551Q)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Mechanical Data**

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.006 grams (Approximate)



### Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel		
MMDT5401Q-7-F Automotive		K4M	7	8	3,000		
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS). 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.							

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

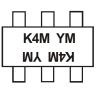
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### Marking Information

### SOT363



K4M = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018)M = Month (ex: 9 = September)

Vear	y 2017	20	18	2019	2020	20	21	2022	2023	20	24	2025
Code	E	F	-	G	Н			J	K	l	_	М
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-160	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-150	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Continuous Collector Current	Ι <sub>C</sub>	-200	mA

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)	D-	200		
Power Dissipation	(Notes 7 & 8)	PD	320	mW	
Thermal Desistance, Junction to Ambient	(Note 6)	D	625		
Thermal Resistance, Junction to Ambient	(Notes 7 & 8)	$R_{ extsf{ heta}JA}$	390	°C/W	
Thermal Resistance, Junction to Case (Note 9)		R <sub>0JC</sub>	140		
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition		
OFF CHARACTERISTICS								
Collector-Base Breakdown Voltage	<b>BV</b> CBO	-160	_	_	V	$I_{C} = -100 \mu A, I_{E} = 0$		
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	-150			V	$I_{C} = -1mA, I_{B} = 0$		
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-6			V	$I_E = -100 \mu A, I_C = 0$		
Collector-Base Cutoff Current				-50	nA	$V_{CB} = -120V, I_E = 0$		
Collector-Base Cuton Current	I <sub>CBO</sub>	_		-50	μA	$V_{CB} = -120V, I_E = 0, T_A = +100^{\circ}C$		
Base-Emitter Cutoff Current	I <sub>EBO</sub>	_		-50	nA	$V_{EB} = -5V, I_{C} = 0$		
ON CHARACTERISTICS (Note 10)								
	h <sub>FE</sub>	50			_	$I_{C} = -1.0mA, V_{CE} = -5.0V$		
DC Current Gain		60	—	240		$I_{C} = -10mA, V_{CE} = -5.0V$		
		50				$I_{C} = -50mA, V_{CE} = -5.0V$		
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	—	-0.2	v	$I_{C} = -10mA, I_{B} = -1.0mA$		
				-0.5		$I_{C} = -50mA, I_{B} = -5.0mA$		
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	_	-1.0	V	$I_{C} = -10mA, I_{B} = -1.0mA$		
Base-Emilier Saturation voltage						$I_{C} = -50 \text{mA}, I_{B} = -5.0 \text{mA}$		
SMALL SIGNAL CHARACTERISTICS								
Output Capacitance	Cobo	_		6.0	pF	$V_{CB} = -10V$ , f = 1.0MHz, I <sub>E</sub> = 0		
Small Signal Current Gain	h <sub>fe</sub>	40		260		$I_{C} = -1mA$ , $V_{CE} = -10V$ , $f = 1.0MHz$		
Current Gain-Bandwidth Product	f⊤	100	—	300	MHz	$I_{C} = -10 \text{mA}, V_{CE} = -10 \text{V}, f = 100 \text{MHz}$		
Noise Figure	NF		_	8.0	dB	$\label{eq:Vce} \begin{split} V_{CE} &= -5.0V, \ I_C = -200 \mu A, \\ R_S &= 10\Omega, \ f = 1.0 \text{kHz} \end{split}$		

6. For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

7. Same as Note 6, except the device is mounted on 25mm x 25mm 2oz copper.

8. Maximum combined dissipation.

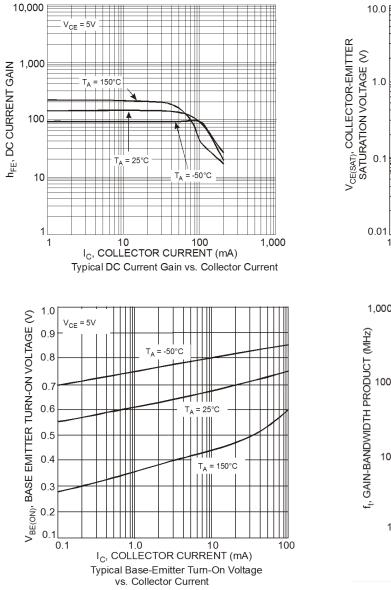
9. Thermal resistance from junction to the top of package.

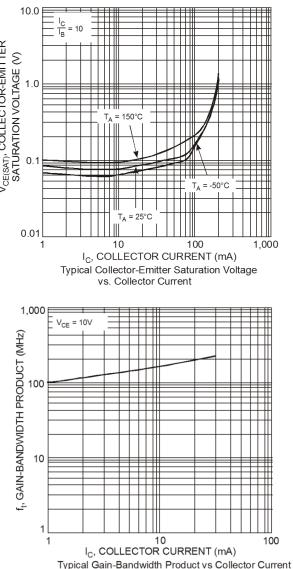
10. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.

Notes:



### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

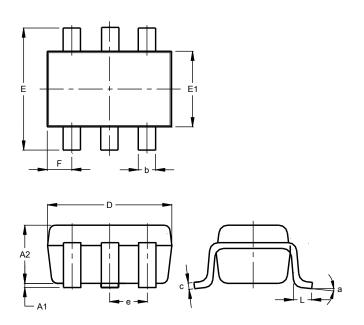






## **Package Outline Dimensions**

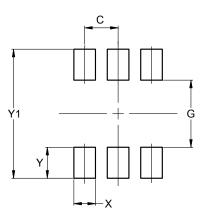
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.10	0.30	0.25				
С	0.10	0.22	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	0.650 BSC						
F	0.40	0.45	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All	All Dimensions in mm						

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	0.650			
G	1.300			
Х	0.420			
Y	0.600			
Y1	2.500			

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

SOT363

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